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Vishay Siliconix

Automotive P-Channel 30 V (D-S) 175 °C MOSFET



PRODUCT SUMMARY					
V _{DS} (V)	-30				
$R_{DS(on)}(\Omega)$ at $V_{GS} = -10 \text{ V}$	0.0044				
$R_{DS(on)}(\Omega)$ at $V_{GS} = -4.5 \text{ V}$	0.0071				
I _D (A)	-60				
Configuration	Single				

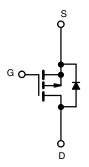
FEATURES

- TrenchFET® power MOSFET
- AEC-Q101 qualified
- 100 % R_q and UIS tested
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912





ROHS COMPLIANT HALOGEN FREE



P-Channel MOSFET

ORDERING INFORMATION	
Package	PowerPAK SO-8L
Lead (Pb)-free and halogen-free	SQJ407EP (for detailed order number please see www.vishay.com/doc?79771)

PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V_{DS}	-30	V	
Gate-source voltage		V_{GS}	± 20		
Continuous drain current	T _C = 25 °C a	ı	-60		
Continuous drain current	T _C = 125 °C	I _D	-56		
Continuous source current (diode conduction)	а	I _S	-60	Α	
Pulsed drain current ^b		I _{DM}	-155		
Single pulse avalanche current		I _{AS}	-41		
Single pulse avalanche energy	L = 0.1 mH	E _{AS}	84	mJ	
Maximum power dissipation ^b	T _C = 25 °C	D	68	W	
	T _C = 125 °C	P_{D}	22		
Operating junction and storage temperature range		T _J , T _{stg}	-55 to +175	90	
Soldering recommendations (peak temperature) d, e		•	260	°C	

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-ambient PC	CB mount ^c	R_{thJA}	68	°C/W
Junction-to-case (drain)		R_{thJC}	2.2	C/VV

Notes

- a. Package limited
- b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %
- c. When mounted on 1" square PCB (FR4 material)
- d. See solder profile (www.vishay.com/doc?73257). For PowerPAK SO-8L, the end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection
- e. Rework conditions: manual soldering with a soldering iron is not recommended for leadless components



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PARAMETER	SYMBOL	TES	T CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static		<u> </u>					
Drain-source breakdown voltage	V _{DS}	$V_{GS} = 0$, $I_D = -250 \mu A$		-30		-	V
Gate-source threshold voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$		-1.5	-2.0	-2.5	V
Gate-source leakage	I _{GSS}	V _{DS} =	$0 \text{ V}, \text{ V}_{GS} = \pm 20 \text{ V}$	-	-	± 100	nA
		V _{GS} = 0 V	V _{DS} = -30 V	-	-	-1	
Zero gate voltage drain current	I_{DSS}	V _{GS} = 0 V	V _{DS} = -30 V, T _J = 125 °C	=	-	-50	μΑ
		V _{GS} = 0 V	V _{DS} = -30 V, T _J = 175 °C	-	-	-200	
On-state drain current ^a	I _{D(on)}	V _{GS} = -10 V	V _{DS} ≥ -5 V	-30	-	-	Α
		V _{GS} = -10 V	I _D = -10 A	-	0.0036	0.0044	- Ω
Drain actives on state resistance 3	В	V _{GS} = -10 V	I _D = -10 A, T _J = 125 °C	-	-	0.0060	
Drain-source on-state resistance ^a	$R_{DS(on)}$	V _{GS} = -10 V	I _D = -10 A, T _J = 175 °C	-	-	0.0068	
		V _{GS} = -4.5 V	I _D = -6 A	-	0.0059	0.0071	
Forward transconductance b	9 _{fs}	V _{DS} =	-15 V, I _D = -10 A	-	60	-	S
Dynamic ^b					•		,
Input capacitance	C _{iss}		V _{DS} = -25 V, f = 1 MHz	-	8200	10 700	pF
Output capacitance	C _{oss}	V _{GS} = 0 V		-	950	1300	
Reverse transfer capacitance	C _{rss}	1		-	785	1050	
Total gate charge ^c	Qg			-	169	260	
Gate-source charge ^c	Q _{gs}	V _{GS} = -10 V	$V_{DS} = -15 \text{ V}, I_{D} = -5 \text{ A}$	-	24	-	nC
Gate-drain charge ^c	Q _{gd}	1		-	32	-	
Gate resistance	R_g		f = 1 MHz	0.5	1.05	1.6	Ω
Turn-on delay time ^c	t _{d(on)}		$V_{DD} = -15 \text{ V}, R_{L} = 3 \Omega$		23	35	- ns
Rise time ^c	t _r	V _{DD} :			19	30	
Turn-off delay time ^c	t _{d(off)}	$I_D \cong -5 \text{ A}, V_{GEN} = -10 \text{ V}, R_g = 1 \Omega$		-	72	120	
Fall time ^c	t _f				14	25	
Source-Drain Diode Ratings and Charac	teristics b	•					
Pulsed current ^a	I _{SM}				-	-155	Α
Forward voltage	V _{SD}	I _F =	I _F = -10 A, V _{GS} = 0 V		-0.75	-1.2	V
Body diode reverse recovery time	t _{rr}			-	39	90	ns
Body diode reverse recovery charge	Q _{rr}	1	1		45	100	nC
Reverse recovery fall time	t _a	I _F = 10 A, di/dt = 100 A/μs		-	22	-	
Reverse recovery rise time	t _b	7		_	19	-	ns
					<u> </u>	l	

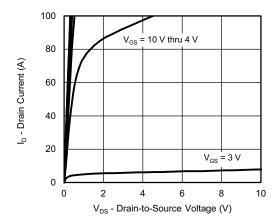
Notes

- f. Pulse test; pulse width $\leq 300~\mu s,~duty~cycle \leq 2~\%$
- g. Guaranteed by design, not subject to production testing
- h. Independent of operating temperature

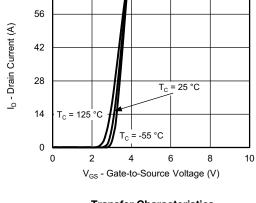
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)

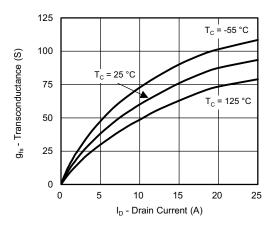


Output Characteristics

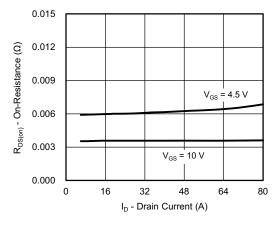


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Transfer Characteristics

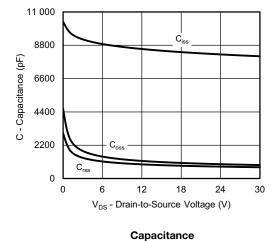


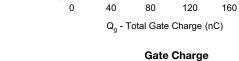
Transconductance



On-Resistance vs. Drain Current

200





10

8

6

2

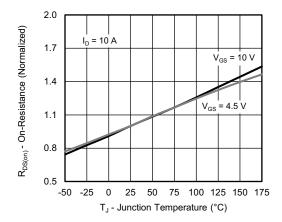
0

I_D = 5 Å V_{DS} = 18

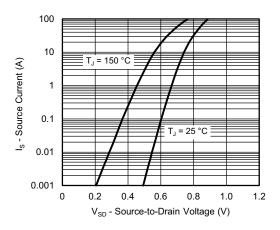
V_{GS} - Gate-to-Source Voltage (V)



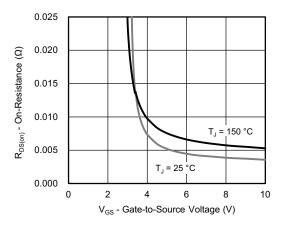
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



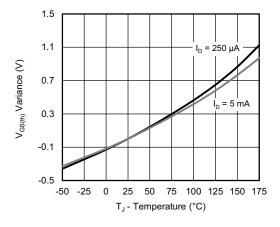
On-Resistance vs. Junction Temperature



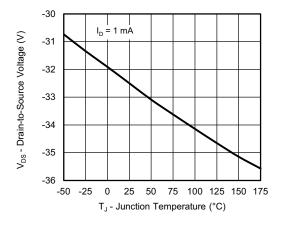
Source Drain Diode Forward Voltage



On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage

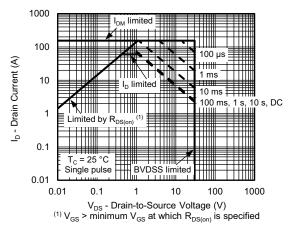


Drain-Source Breakdown vs. Junction Temperature

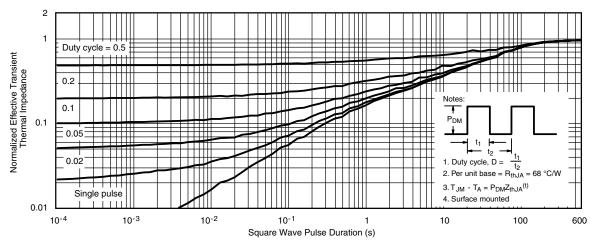
For technical questions, contact: automostech



THERMAL RATINGS (T_C = 25 °C, unless otherwise noted)



Safe Operating Area

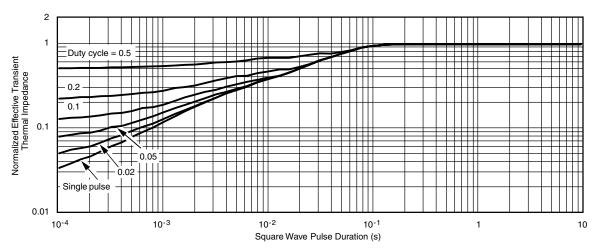


Normalized Thermal Transient Impedance, Junction-to-Ambient

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THERMAL RATINGS (T_C = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?62806.



PowerPAK® SO-8L Case Outline 2





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DIM	MILLIMETERS			INCHES				
DIM.	MIN.	NOM.	MAX.	MIN.	NOM.	MAX		
Α	1.00	1.07	1.14	0.039	0.042	0.045		
A1	0.00	-	0.127	0.00	-	0.005		
b	0.33	0.41	0.48	0.013	0.016	0.019		
b1	0.44	0.51	0.58	0.017	0.020	0.023		
b2	4.80	4.90	5.00	0.189	0.193	0.197		
b3		0.094			0.004			
b4		0.47			0.019			
С	0.20	0.25	0.30	0.008	0.010	0.012		
D	5.00	5.13	5.25	0.197	0.202	0.207		
D1	4.80	4.90	5.00	0.189	0.193	0.197		
D2	3.86	3.96	4.06	0.152	0.156	0.160		
D3	1.63	1.73	1.83	0.064	0.068	0.072		
е		1.27 BSC			0.050 BSC			
Е	6.05	6.15	6.25	0.238	0.242	0.246		
E1	4.27	4.37	4.47	0.168	0.172	0.176		
E2	2.75	2.85	2.95	0.108	0.112	0.116		
E3	6.05	6.22	6.40	0.238	0.245	0.252		
F	-	-	0.15	-	-	0.006		
L	0.62	0.72	0.82	0.024	0.028	0.032		
L1	0.92	1.07	1.22	0.036	0.042	0.048		
K		0.51		0.020				
W	0.23			0.009				
W1		0.41		0.016				
W2	2.82			0.111				
W3		2.96			0.117			
θ	0°	-	10°	0°	-	10°		

DWG: 6044

Note

• Millimeters will govern



RECOMMENDED MINIMUM PAD FOR PowerPAK® SO-8L SINGLE



Recommended Minimum Pads Dimensions in mm (inches)



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